## RF Small-Signal Transistors



Motorola's small-signal, low power RF transistor product range includes transistors with gain-bandwidths of 1.0 GHz to 8.0 GHz operating at currents of 0.25 mA to over 140 mA.

These devices are available in a wide variety of package types; metal can, plastic Macro-X and Macro-T, hermetic ceramic and microminiature. Most of these transistors are fully characterized with y or s parameters; and in addition, there are non-saturated switching characteristics, low power driver specifications, and noise figure limits. QPL types with JAN, JTX and JTXV processing levels are available as well as Hi Rel processing to meet unique customer requirements.



**RF Small-Signal Transistors** 

Motorola small-signal and rnedium power RF transistors with gain-bandwidth products from 1.0 GHz to 8.0 GHz operate with currents from 0.25 mA to over 140 mA. The following chart, combined with the tables of package options, enables the circuit designer to select the optimum device from Motorola's wide range of transistor/package combinations.

- 2N3866, 2N3866A
- 2 2N5160, MM4018, PNP 3 2N3948, 2N4427, MRF207
- 3 2N3948, 2N4427, MRF2 4 2N5109, 2N5943
- 5 2N5583, PNP
- 6 2N5836, 2N5837
- 7 MRF511, MRF517, MRF525
- 8 2N2857. 2N3839, 2N5179,
- MRF501, MRF502
- 9 BFX89, BFY90

- 10 2N4957, 2N4958, 2N4959, PNP 12 2N6603, BFR90, MRF901, MRF904
- 13 2N6604, BFR91, MRF911, MRF914
- 14 BFR96, MRF961, MRF962, MRF965
- 15 BFW92A
- 16 MRF559
- 17 MRF580, MRF581, MRF586, MRF587
- 18 MRF571, MRF572
- 19 MRF536, MRF534, MM4049, PNP

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## **RF SMALL-SIGNAL TRANSISTORS (continued)**

## CATV, MATV, and Class A Linear Transistors

The devices listed below are excellent for Class A linear CATV/MATV applications and are listed according to increasing gainbandwidth ( $f_T$ ). More information concerning the device for your specific linear design needs can be obtained through your local Motorola Sales Office or Motorola distributor.

Device Type	Nominal Test Conditions VCE <sup>/1</sup> C Volts/mA	f <sub>T</sub> MHz Min	Noise Figure Max/Freq. dB/MHz	Distortion Specifications				
				2nd Order IMD	3rd Order IMD	12 Ch. Cross- Mod.	Output Level dBmV	Package
MRF501	6/5	600	4.5*/200					TO-72
MRF502	6/5	800	4.0*/200					TO-72
2N5179	6/5	900	4.5/200					TO-72
BFY90	5/2	1000	5.0/500					TO-72
BFX89	5/25	1200	6.5/500					TO-72
2N5109	15/50	1200	3.0*/200					TO-39
2N5943	15/50	1200	3.4/200	- 50		- 42	+ 50	TO-39
MRF511	20/80	1500	7.3*/200	~ 50	- 65	- 57	+ 50	244A-01
MRF517	15/60	2200	7.5/300	- 60	- 72	- 57	+ 45	TO-39
BFW92A	5/2	4500*	3.0*/500					317A-01
MRF586	14/70	4500*	3.0/500	- 50	~ 72		+ 50	TO-39
BFR90	10/14	5000*	2.4*/500					317A-01
BFR91	5/35	5000*	1.9*/500					317A-01
BFR96	10/50	5000*	3.0*/500					317A-01
MRF961	10/50	5000*	2.0*/500					317-01
MRF962	10/50	5000*	2.0*/500					303-01
MRF965	10/50	5000*	2.0*/500					TO-46
MRF581	10/75	5000*	3.0/500	, <u> </u>	- 65		+ 50	317-01
MRF587	14/70	5500*	3.0/500	- 52	- 72		+ 50	244A-01

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## **High-Speed Switches**

The transistors listed below are for use as high-frequency current-mode switches. They are also suitable for RF amplifier and oscillator applications. The devices are listed in ascending order of collector current.

Device Type	Test Conditions IC/VCE mA/Volts	f <del>T</del> MHz Min	<sup>г</sup> ь́ <sup>С</sup> С Мах	Package
2N3959	10/10	1300	25	TO-18
2N3960	10/10	1600	40	TO-18
2N5835	10/6.0	2500	5.0**	TO-72
MM4049*	20/5.0	4000	15	TO-72
MRF914	20/10	4500**		TO-72
2N5943	50/15	1200	5.5**	TO-39
2N5583*	50/10	1000	8.0**	TO-39
2N5836	50/6.0	2000	6.0**	TO-46
2N5837	100/3.0	1700	6.0**	TO-46

\*PNP \*\*Typ